TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX244F,TC74LCX244FT,TC74LCX244FK

### Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX244 is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

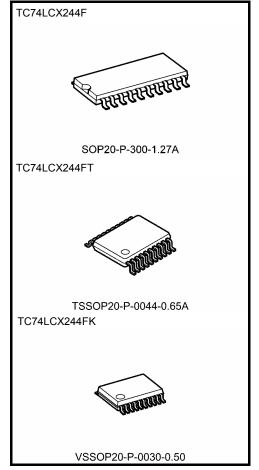
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The 74LCX244F/FT is a non-inverting 3-state buffer having two active-low output enables. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

#### **Features**

- Low-voltage operation: V<sub>CC</sub> = 2.0 to 3.6 V
- High-speed operation:  $t_{pd} = 6.5 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Ouput current:  $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 244 type



Weight

SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

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2Y4

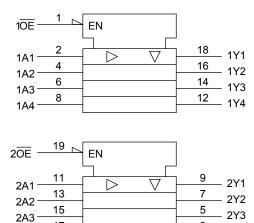
### Pin Assignment (top view)

#### 10E 20 $V_{CC}$ 1A1 19 2OE 2Y4 18 1Y1 1A2 2A4 2Y3 5 1Y2 1A3 6 2A3 2Y2 7 1Y3 1A4 2A2 2Y1 9 12 1Y4 GND 10 2A1

### **IEC Logic Symbol**

17

2A4



**Truth Table** 

Inp	uts	Outputs
ŌĒ	An	Outputs
L	L	L
L	Н	Н
Н	Х	Z

X: Don't care

Z: High impedance

### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5	V
		(Note 3)	
Input diode current	lık	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc



### **Operating Ranges (Note 1)**

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	2.0 to 3.6	V	
Power supply voltage	vCC	1.5 to 3.6 (Note 2)	V	
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	Vout	0 to 5.5 (Note 3)	V	
Output voltage	VOU1	0 to V <sub>CC</sub> (Note 4)	<b>v</b>	
Output current	I <sub>OH</sub> /I <sub>OI</sub>	±24 (Note 5)	mA	
Output current	IOH/IOL	±12 (Note 6)	ША	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 6:  $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$ 

Note 7:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V

#### **Electrical Characteristics**

### DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteri	stics	Symbol	Test Condition			Min	Max	Unit	
					V <sub>CC</sub> (V)				
Input voltage	H-level	V <sub>IH</sub>	-	_	2.7 to 3.6	2.0	_	V	
input voitage	L-level	V <sub>IL</sub>	-	_	2.7 to 3.6	_	0.8	V	
			$I_{OH} = -100 \mu A$	2.7 to 3.6	V <sub>CC</sub> - 0.2				
	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_		
				I <sub>OH</sub> = -18 mA	3.0	2.4	_		
Output voltage				I <sub>OH</sub> = -24 mA	3.0	2.2	_	V	
				I <sub>OL</sub> = 100 μA	2.7 to 3.6	_	0.2		
	.,,		I <sub>OL</sub> = 12 mA	2.7	_	0.4			
	L-level	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 16 mA	3.0	_	0.4		
				I <sub>OL</sub> = 24 mA	3.0	_	0.55		
Input leakage curren	t	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μА	
0 -4-44-4-5	3-state output off-state current I <sub>OZ</sub>		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>				^	
3-state output oπ-sta			V <sub>OUT</sub> = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μА	
Power off leakage cu	rrent	l <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	_	10.0	μА	
Ouisseent supply su	rant	Ι.	V <sub>IN</sub> = V <sub>CC</sub> or GND		V <sub>IN</sub> = V <sub>CC</sub> or GND		_	10.0	
Quiescent supply cur	ient	ICC	V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μА	
Increase in I <sub>CC</sub> per in	nput	Δlcc	V <sub>IH</sub> = V <sub>CC</sub> - 0.6		2.7 to 3.6	_	500		

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### AC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	_	7.5	ns
Tropagation delay time	t <sub>pHL</sub>	i igure 1, i igure 2	$3.3 \pm 0.3$	1.5	6.5	115
Outrout analyla times	t <sub>pZL</sub>	Figure 1, Figure 3	2.7	_	9.0	ns
Output enable time	t <sub>pZH</sub>		$3.3 \pm 0.3$	1.5	8.0	
Output disable time	t <sub>pLZ</sub>	Figure 4 Figure 2	2.7	_	8.0	ns
Output disable time	t <sub>pHZ</sub>	Figure 1, Figure 3	$3.3 \pm 0.3$	1.5	7.0	115
Output to output alcour	t <sub>osLH</sub>	(NI-do)	2.7			ne
Output to output skew	t <sub>osHL</sub>	(Note)	$3.3 \pm 0.3$		1.0	ns

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$ 

### Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ $\Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic $V_{OL}$	$V_{OLP}$	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V

### **Capacitive Characteristics (Ta = 25°C)**

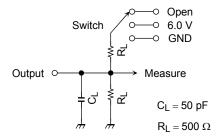
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>	_	3.3	7	pF
Output capacitance	C <sub>OUT</sub>	_	3.3	8	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note	3.3	25	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$ 

#### **AC Test Circuit**



Parameter	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
t <sub>pLZ</sub> , t <sub>pZL</sub>	6.0 V
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND

Figure 1

#### **AC Waveform**

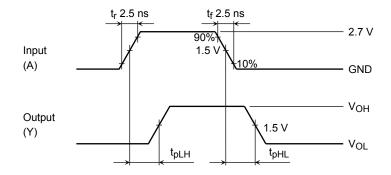


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

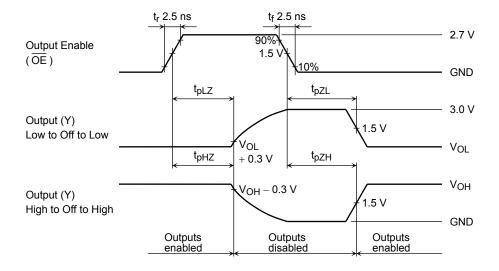
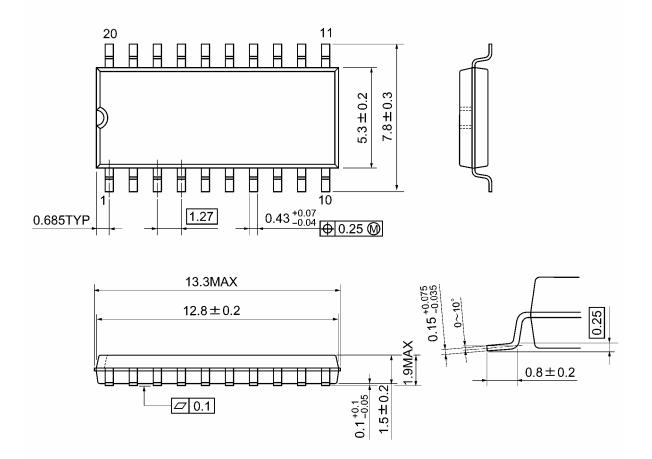


Figure 3  $t_{\text{pLZ}},\,t_{\text{pHZ}},\,t_{\text{pZL}},\,t_{\text{pZH}}$ 

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## **Package Dimensions**

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

## **Package Dimensions**

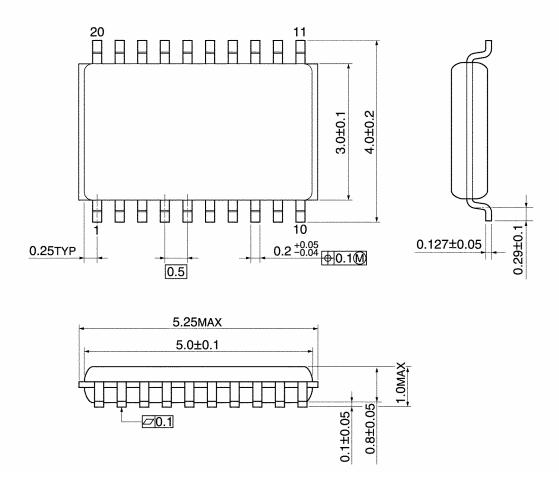
TSSOP20-P-0044-0.65A Unit: mm  $6.4\pm0.2$  $0.22\substack{+0.09 \\ -0.06}$ 0.65 0.325TYP <del>| |</del>0.13M 6.9MAX 6.5±0.1 1.2MAX 0~10 1.0±0.05 0.1±0.05 S **∅**0.1|S (0.5)

Weight: 0.08 g (typ.)

0.45~0.75

## **Package Dimensions**

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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